

Form 1449 (Modified)

Atty Docket No.

Serial No.:

Information Disclosure  
Statement By Applicant

MAT-6

10/723,386

Applicants:

Savas, et al

Filing Date

November 26, 2003

Group

1752 1763

Use Several Sheets if Necessary)

## U.S. Patent Documents

Examiner Initial	No.	Patent No.	Date	Patentee	Class	Sub- class	Filing Date
<i>WJ</i>	A	4,028,135	6/7/1977	Vig et al			
<i>WJ</i>	B	4,782,267	11/1/1988	Collins et al			
<i>WJ</i>	C	5,234,540	8/10/1993	Grant et al			
<i>WJ</i>	D	5,954,884	11/21/1999	Lawing et al			
<i>WJ</i>	E	6,015,503	1/18/2000	Butterbaugh et al			
<i>WJ</i>	F	6,124,211	11/26/2000	Butterbaugh et al			
<i>WJ</i>	G	US 6,183,566 B1	2/6/2001	Lawing et al			
<i>WJ</i>	H	US 6,277,767 B1	8/21/2001	Shiramizu et al			

## Foreign Patent or Published Foreign Patent Application

Examiner Initial	No.	Document No.	Publication Date	Country or Patent Office	Class	Sub- class	Translation	
							Yes	No
	I							
	J							
	K							

## Other Documents

Examiner Initial	No.	Author, Title, Date, Place (e.g. Journal) of Publication
<i>WJ</i>	L	Torek et al; UV/Fluorine Etching of Native Silicon Oxides; 1992; Proceedings of the Second International Symposium on Cleaning Technology in Semiconductor Device Manufacturing; pp 80-86.
<i>WJ</i>	M	Ito et al; Wafer Purification by Photochemical Dry Cleaning; March 1989, Semiconductor World; pp120-123
<i>WJ</i>	N	Zhang et al; Large Area Photochemical Dry Etching of Polyimide; 1993; Applied Surface Science; Vol 69; pp 299-304
<i>WJ</i>	O	Vig; Ultraviolet-Ozone Cleaning of Semiconductor Surfaces; January 1992; US Army Laboratory Command (LAPCOM) Technical Report
Examiner		Date Considered
<i>maureen J. Thomas</i>		03/02/2006

Examiner: Initial citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.